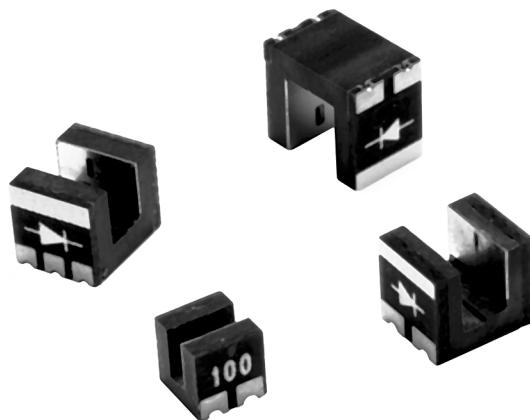




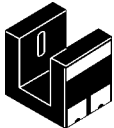

EE-SX1107/1108/1109/1131

Ultra-Compact Photomicrosensors with Surface-Mount Design

- Surface mount design, and tape and reel packaging facilitate automated PCB assembly
- Compact size makes these sensors ideal for use in applications with restricted space
- High-resolution sensing with phototransistor output
- Dual channel model that is ideal for encoder applications (EE-SX1131)



Ordering Information

Appearance	Sensing method	Slot width	Slot depth	Sensing object	Weight	Part number
	Transmissive	1 mm	2 mm	Opaque 0.15 x 0.6 mm min.	0.05 g	EE-SX1107
		2 mm	2.8 mm	Opaque 0.3 x 1.0 mm min.	0.1 g	EE-SX1108
		3 mm	3.5 mm	Opaque 0.5 x 1.0 mm min.	0.1 g	EE-SX1109
	Dual channel transmissive	2 mm	2.8 mm	Opaque 0.3 x 1.0 mm min.	0.1 g	EE-SX1131

Specifications

■ ABSOLUTE MAXIMUM RATING ($T_A=25^{\circ}\text{C}$)

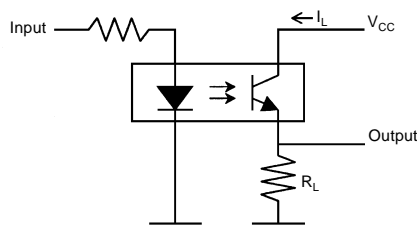
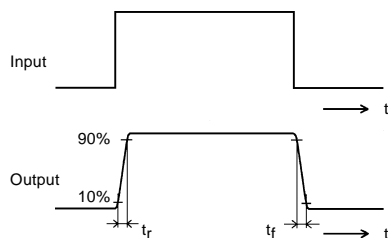
Item		Symbol	Rated value
Emitter	Forward current	I_F	25 mA (see note)
	Pulse forward current	I_{FP}	100 mA (duty: 1/100, pulse width: 0.1 ms)
	Reverse voltage	V_R	5 V
Detector	Collector-emitter voltage	V_{CEO}	20 V
	Emitter-collector voltage	V_{ECO}	5 V
	Collector current	I_C	20 mA
	Collector dissipation	P_C	75 mW (see note)
Ambient temperature	Operating	T_{opr}	-30° to 85°C
	Storage	T_{stg}	-40° to 90°C
	Soldering (manual)	T_{sol}	300°C (3 second max.)
	Soldering (reflow)	T_{sol}	240°C (10 second max)

Note: Refer to Engineering Data if the ambient temperature is not within the normal room temperature range.

■ CHARACTERISTICS ($T_A=25^{\circ}\text{C}$)

Item		Symbol	Value	Condition
Emitter	Forward voltage	V_F	1.1 V typ., 1.3 V max.	$I_F = 5 \text{ mA}$
	Reverse current	I_R	10 μA max.	$V_R = 5 \text{ V}$
	Peak emission wavelength	$\lambda_P(L)$	940 nm typ.	$I_F = 20 \text{ mA}$
Detector	Dark current	I_D	100 nA max.	$V_{CE} = 10 \text{ V}$, 0 lx
	Peak spectral sensitivity wavelength	$\lambda_P(P)$	900 nm typ.	—
Combination	Light current (collector-current)	I_L	50 μA min., 150 μA typ., 500 μA max.	$I_F = 5 \text{ mA}$, $V_{CE} = 5 \text{ V}$
	Collector-emitter saturation voltage	$V_{CE}(\text{sat})$	0.1 V typ., 0.4 V max.	$I_F = 20 \text{ mA}$, $I_L = 50 \mu\text{A}$
	Rising time	t_r	10 μs typ. (see note)	$V_{CC} = 5 \text{ V}$, $R_L = 1 \text{ k}\Omega$
	Falling time	t_f	10 μs typ. (see note)	

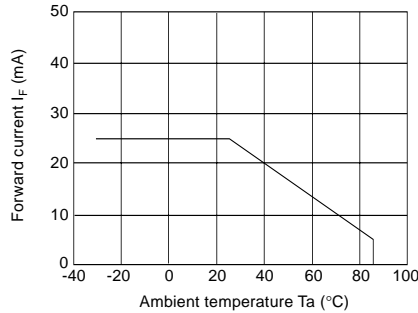
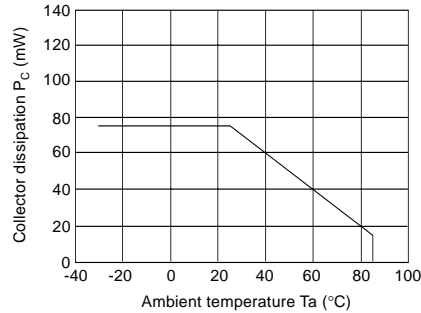
Note: The following figures show the rising time (t_r) and falling time (t_f).



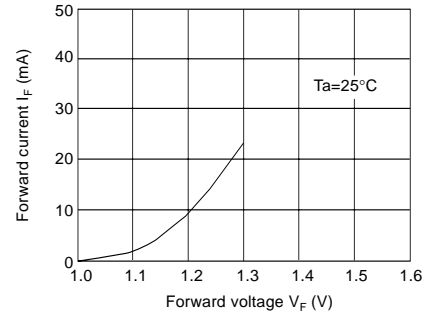
Engineering Data

Note: The operating conditions of the photomicrosensor must be within the absolute maximum rating ranges.

■ TEMPERATURE CHARACTERISTICS

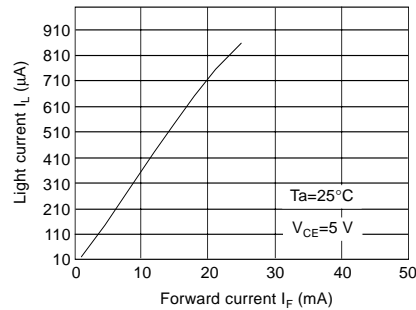


■ INPUT CHARACTERISTICS (TYPICAL)

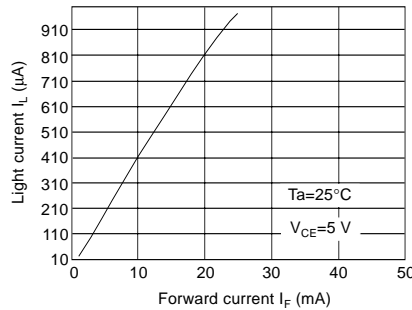


■ INPUT/OUTPUT CHARACTERISTICS (TYPICAL)

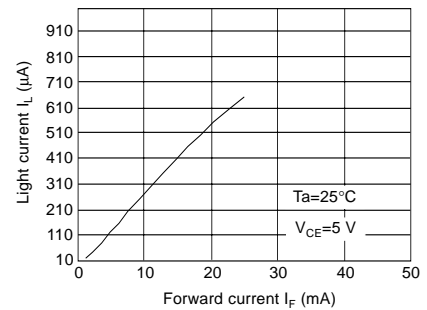
EE-SX1107



EE-SX1108/1131

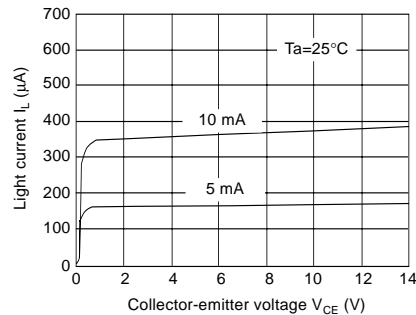


EE-SX1109

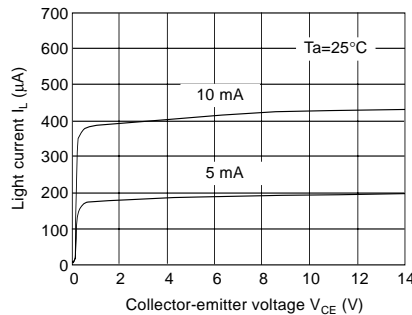


■ OUTPUT CHARACTERISTICS (TYPICAL)

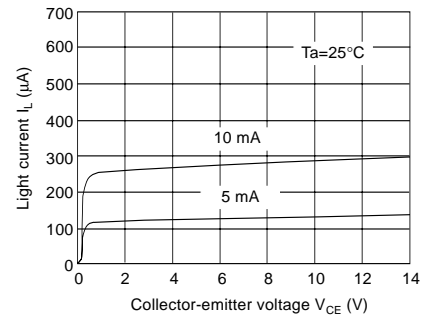
EE-SX1107



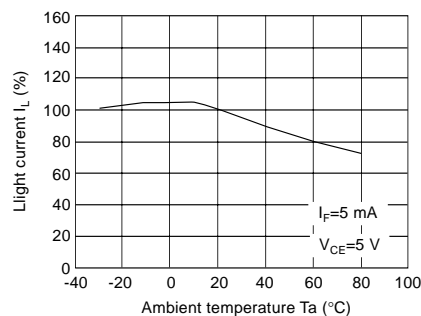
EE-SX1108/1131



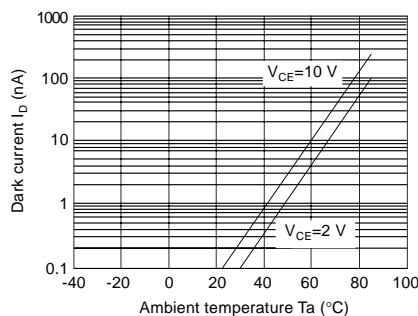
EE-SX1109



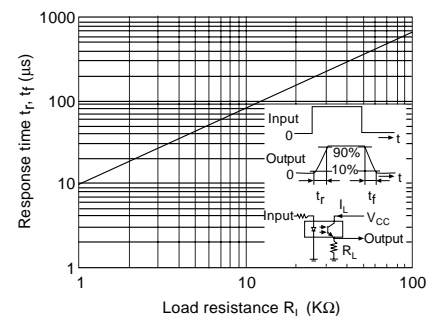
■ LIGHT CURRENT TEMPERATURE DEPENDENCY (TYPICAL)



■ DARK CURRENT TEMPERATURE DEPENDENCY (TYPICAL)

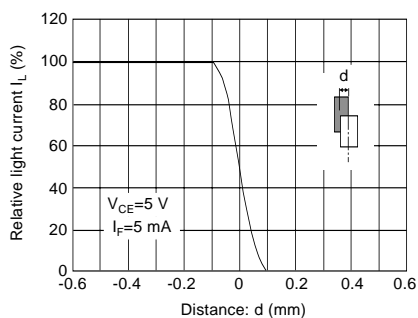
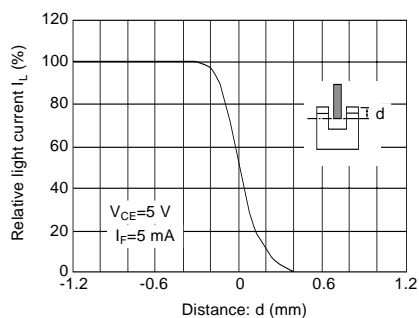


■ RESPONSE TIME CHARACTERISTICS (TYPICAL)

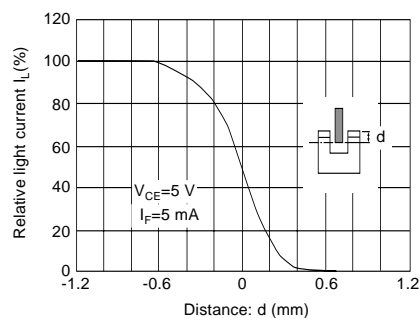


■ SENSING POSITION CHARACTERISTICS (TYPICAL)

EE-SX1107

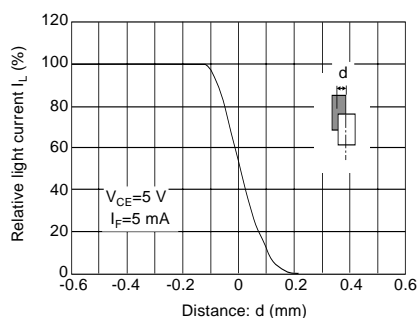


EE-SX1108/1109/1131

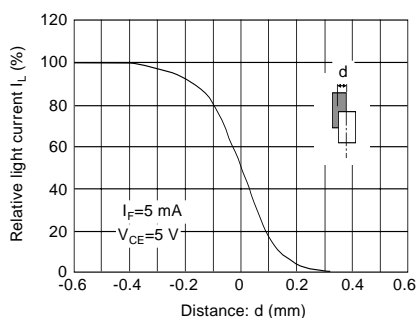


■ SENSING POSITION CHARACTERISTICS (TYPICAL)

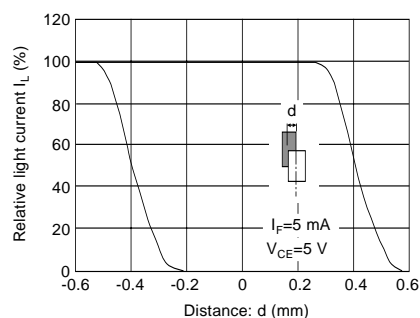
EE-SX1108



EE-SX1109



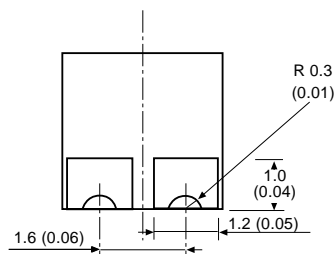
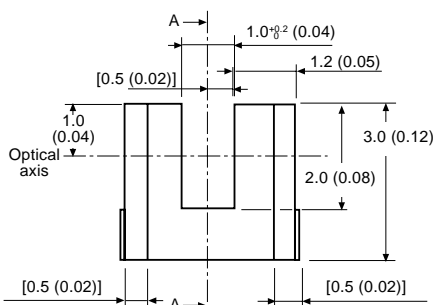
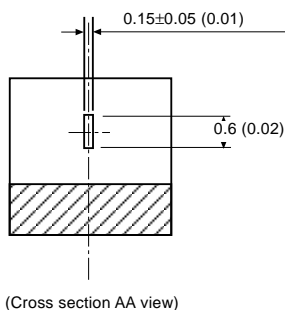
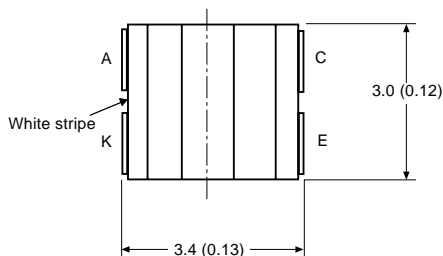
EE-SX1131



Dimensions

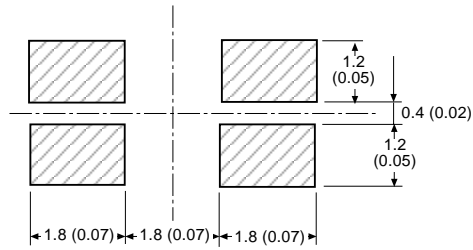
Unit: mm (inch)

■ EE-SX1107

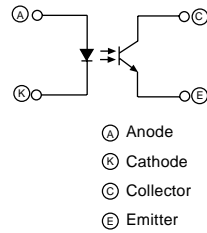


Note: 1. Unless otherwise specified, tolerances are ± 0.15 mm.
2. The values in brackets are relative dimensions.

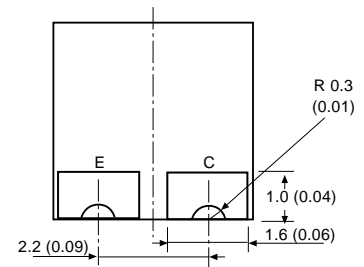
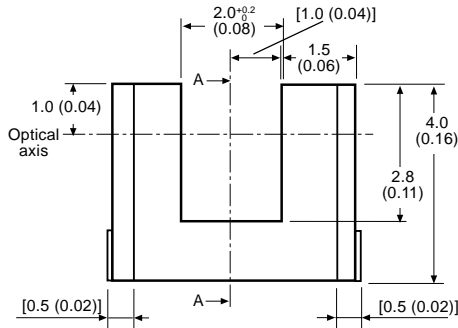
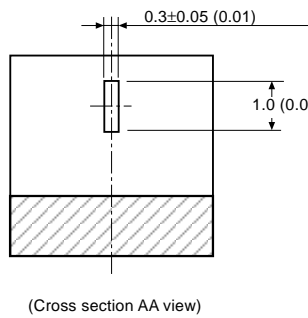
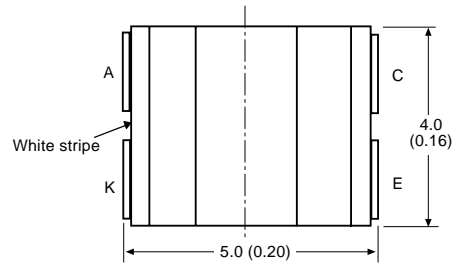
Recommended soldering pattern



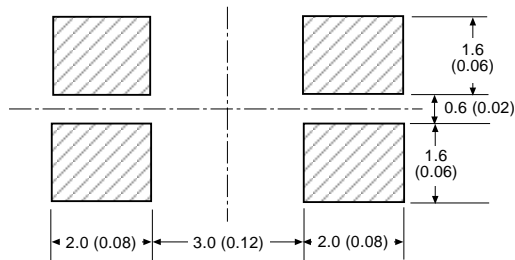
Pin assignment



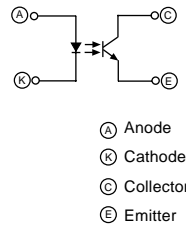
EE-SX1108



Recommended soldering pattern



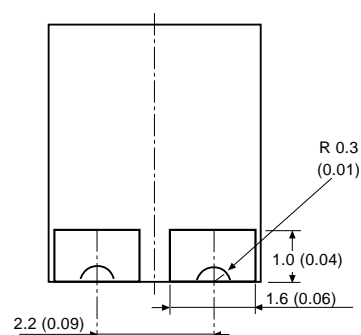
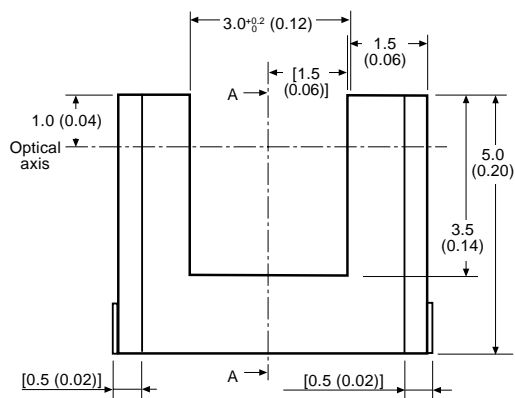
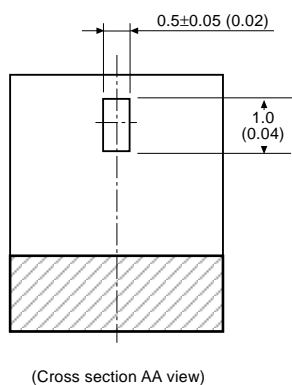
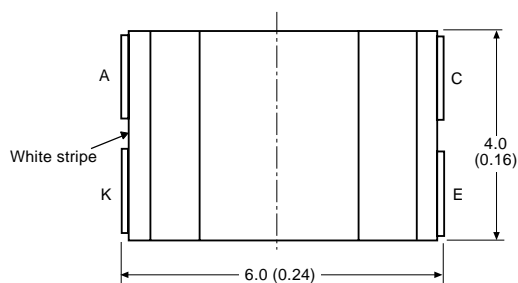
Pin assignment



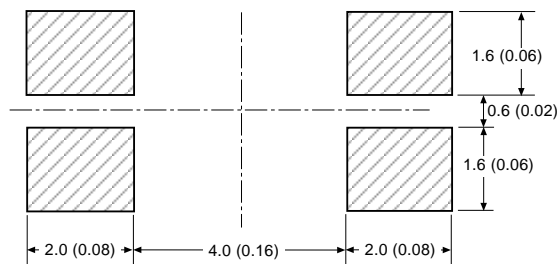
Note: 1. Unless otherwise specified, tolerances are ± 0.15 mm.
2. The values in brackets are relative dimensions.

Unit: mm (inch)

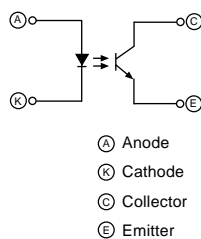
■ EE-SX1109



Recommended soldering pattern

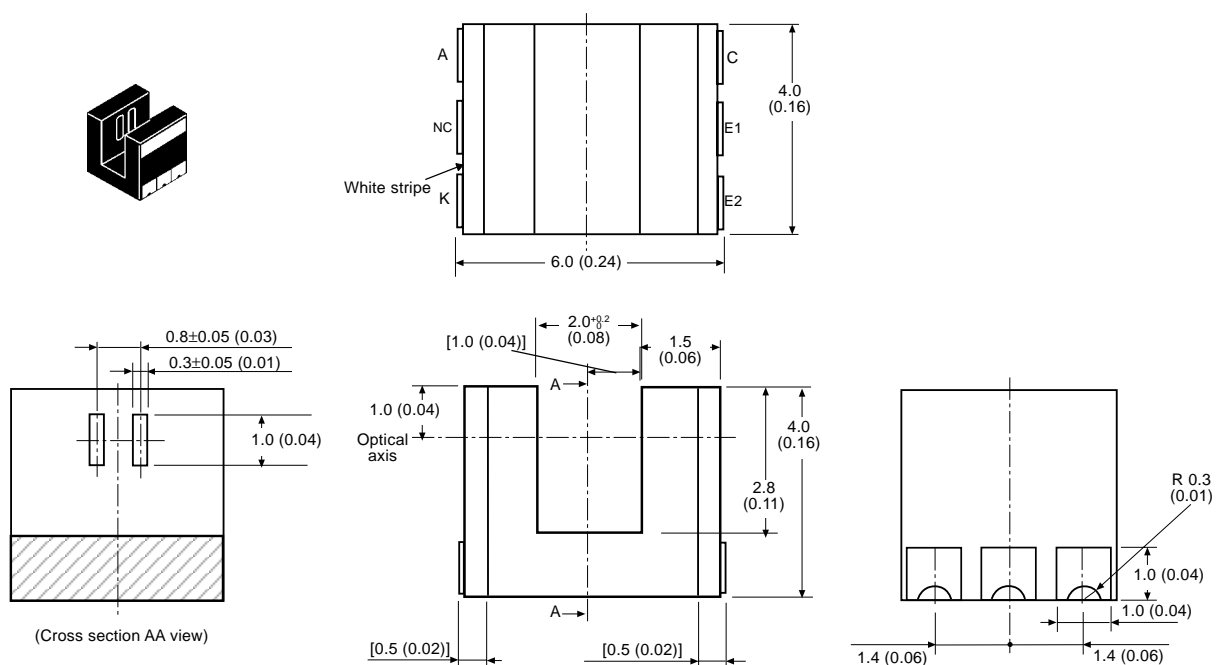


Pin assignment

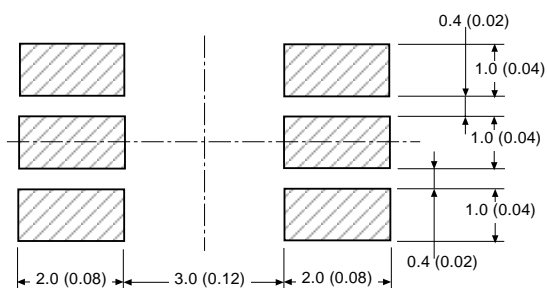


Note: 1. Unless otherwise specified, tolerances are ± 0.15 mm.
 2. The values in brackets are relative dimensions.

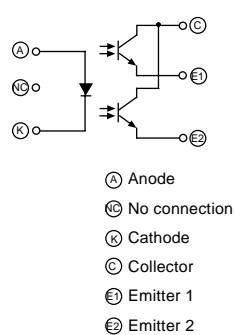
■ EE-SX1131



Recommended soldering pattern



Pin assignment

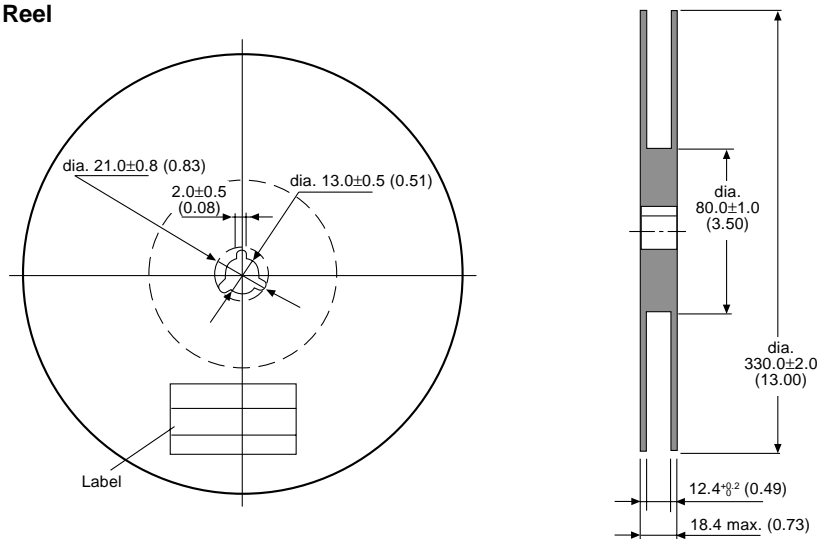


Note: 1. Unless otherwise specified, tolerances are ± 0.15 mm.
 2. The values in brackets are relative dimensions.

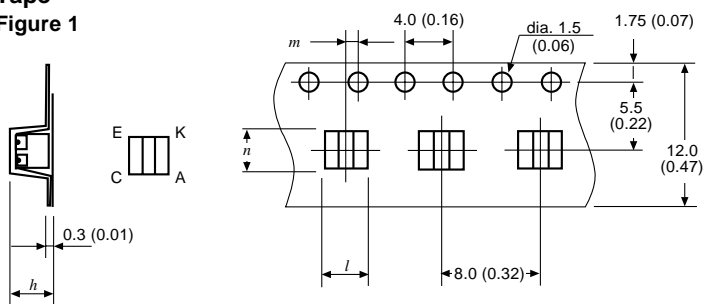
Unit: mm (inch)

■ TAPE AND REEL

Reel

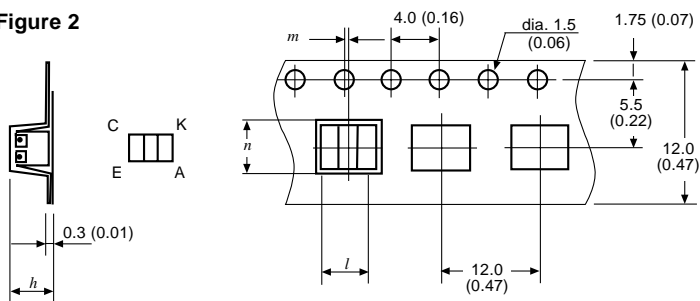


Tape
Figure 1



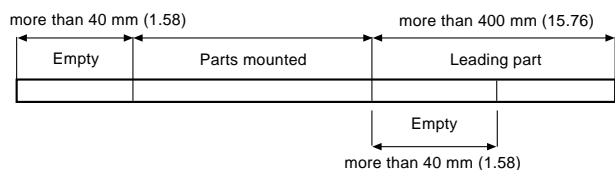
Part number	<i>h</i>	<i>l</i>	<i>m</i>	<i>n</i>
EE-SX1107	3.2 (0.13)	3.6 (0.14)	0.9 (0.04)	3.2 (0.13)
EE-SX1108	4.2 (0.17)	5.2 (0.20)	0.25 (0.01)	4.2 (0.17)
EE-SX1131	4.2 (0.17)	5.2 (0.20)	0.25 (0.01)	4.2 (0.17)

Figure 2



Part number	<i>h</i>	<i>l</i>	<i>m</i>	<i>n</i>
EE-SX1109	5.2 (0.20)	6.2 (0.24)	0.25 (0.01)	4.2 (0.17)

Tape configuration



Quantity per reel

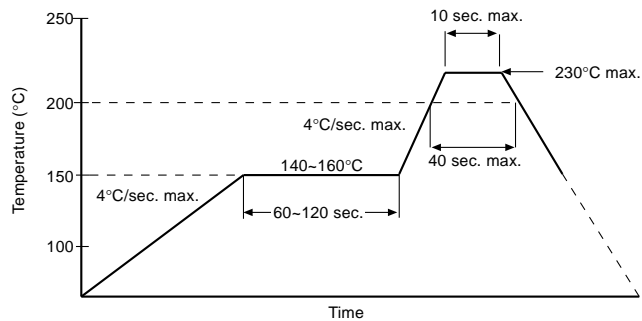
Part number	Pieces per reel
EE-SX1107	2500
EE-SX1108/EE-SX1131	2000
EE-SX1109	1000

Precautions

■ SOLDERING INFORMATION

Reflow soldering

- Reflow soldering must be done within 48 hours after opening the aluminum envelope. The component must be stored under 30°C at 80% RH.
- The following soldering paste is recommended:
Melting temperature: 178~192°C
Composition: Sn 63%, Pb 37%
- Recommended thickness of metal mask is between 0.2 mm and 0.25 mm for screen printing.
- The following chart illustrates the maximum temperature limits for soldering:



Manual soldering

- "Sn 60" (60% tin and 40% lead) or solder with silver content is recommended.
- Use a soldering iron of less than 25W. The temperature of the iron tip must be kept above 300°C (572°F).
- Solder each land for a maximum of 3 seconds.

OMRON

OMRON ELECTRONICS LLC
One East Commerce Drive
Schaumburg, IL 60173
1-800-55-OMRON

OMRON CANADA, INC.
885 Milner Avenue
Scarborough, Ontario M1B 5V8
416-286-6465